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TITLE OF THE INVENTION

MAGNETIC RECORDING MEDIUM AND MAGNETIC
RECORDING/REPRODUCING APPARATUS

BACKGROUND OF THE INVENTION

5 The present invention relates to a perpendicular magnetic recording medium for use in a hard disk drive or the like using the magnetic recording technique and a magnetic recording/reproducing apparatus.

10 A magnetic recording device (HDD) for information recording/reproduction mainly used in computers is used in various fields such as household video decks, audio apparatuses, and car navigation systems because of its large capacity, inexpensiveness, high data access speed, and high data holding reliability. As
15 the range of use of the HDD widens, demands for high storage capacity are increasing, and this has accelerated the competition for the development of a high-density HDD in recent years.

20 Presently commercially available magnetic recording/reproducing apparatuses use a longitudinal magnetic recording method. In this method, magnetic crystal grains forming a perpendicular magnetic recording layer for recording information have an axis of easy magnetization in a direction longitudinal to a
25 substrate. The axis easy magnetization is an axis in the direction of which magnetization easily points. In a Co-based alloy, the axis of easy magnetization is

a direction longitudinal to the normal to the (0001) plane of a hexagonal close-packed structure (hcp) of Co. Decreasing the recording bit area of a longitudinal magnetic recording medium in order to increase the recording density may make the magnetization reversal unit diameter of a recording layer too small. This may worsen the recording/reproduction characteristics by the so-called thermal decay effect which thermally erases information in the magnetic layer. In addition, increasing the density often increases noise produced from the medium by the influence of a demagnetizing field generated in the boundary region between recording bits.

By contrast, in a so-called perpendicular magnetic recording method in which the axis of easy magnetization in a perpendicular magnetic recording layer points in a direction substantially perpendicular to a substrate, the influence of a demagnetizing field between recording bits is small even at high density, and the operation is magnetostatically stable even at a high density. Therefore, the perpendicular magnetic recording method is recently attracting a great deal of attention as a technique which replaces the longitudinal recording method. A perpendicular magnetic recording medium generally comprises a substrate, an alignment control

underlayer which aligns magnetic crystal grains in a perpendicular magnetic recording layer in a (0001) plane and reduces the alignment dispersion, the perpendicular magnetic recording layer containing a hard magnetic material, and a protective layer which protects the surface of the perpendicular magnetic recording layer. In addition, a soft magnetic layer which concentrates magnetic flux generated from a magnetic head during recording is formed between the substrate and alignment control underlayer.

To increase the recording density, noise must be reduced with the thermal stability being maintained in this perpendicular magnetic recording medium as well. The noise reduction method is generally a method which decreases the size of the magnetic crystal grains in the recording layer.

An example of the method of reducing this magnetic interaction is a method which adds SiO_2 and the like to a perpendicular magnetic recording layer to give it a granular structure formed by magnetic crystal grains and a grain boundary region surrounding the magnetic crystal grains and made of the additives, as described in Jpn. Pat. Appln. KOKAI Publication No. 2002-83411.

Unfortunately, these methods alone cannot sufficiently downsize and magnetically isolate the magnetic crystal grains in the recording layer. In

addition to these methods, therefore, there is a disclosed technique which further downsizes the crystal grains in the perpendicular magnetic recording layer by downsizing the crystal grains in the underlayer by adding SiO₂ and the like to it, as described in Jpn. Pat. Appln. KOKAI Publication No. 2003-36525.

If a method like this downsizes the crystal grains in the underlayer, however, the crystallinity and alignment of the underlayer crystal grains generally deteriorate. The influence of this deterioration degrades the crystallinity and (0001) alignment of the crystal grains in the perpendicular magnetic recording layer. As a consequence, the signal-to-noise ratio (SNR) decreases.

BRIEF SUMMARY OF THE INVENTION

The present invention has been made in consideration of the above situation, and has as its object to provide a perpendicular magnetic recording medium having a high signal-to-noise ratio (SNR) and capable of high-density recording by decreasing the average grain size of magnetic crystal grains and improving the crystal alignment of the magnetic crystal grains, and a magnetic recording apparatus using this recording medium.

According to one aspect of the present invention, there is provided a magnetic recording medium

comprising

a substrate,

a soft magnetic layer formed on the substrate,

a multilayered underlayer comprising a first

5 underlayer formed on the soft magnetic layer,

containing copper as a main component, and containing
crystal grains with a face-centered cubic lattice

structure substantially aligned in a (111) plane, and

a second underlayer formed on the first underlayer and

10 containing copper and nitrogen as main components, and

a perpendicular magnetic recording layer formed
on the multilayered underlayer, containing cobalt as a
main component, and containing crystal grains with a
hexagonal close-packed structure substantially aligned

15 in a (0001) plane.

According to a second aspect of the present
invention, there is provided a magnetic
recording/reproducing apparatus comprising

a magnetic recording medium comprising

20 a substrate,

a soft magnetic layer formed on the substrate,

a multilayered underlayer comprising a first

underlayer formed on the soft magnetic layer,

containing copper as a main component, and containing

25 crystal grains with a face-centered cubic lattice

structure substantially aligned in a (111) plane, and

a second underlayer formed on the first underlayer and

containing copper and nitrogen as main components, and

a perpendicular magnetic recording layer formed
on the multilayered underlayer, containing cobalt as a
main component, and containing crystal grains with a
5 hexagonal close-packed structure substantially aligned
in a (0001) plane, and

a recording/reproducing head.

The present invention can perform high-density
recording by using a magnetic recording medium which
10 achieves a high SNR by decreasing the grain size of
magnetic crystal grains in a perpendicular magnetic
recording layer, and improving the alignment of the
magnetic crystal grains.

Advantages of the invention will be set forth in
15 the description which follows, and in part will be
obvious from the description, or may be learned by
practice of the invention. Advantages of the
invention may be realized and obtained by means of the
instrumentalities and combinations particularly
20 pointed out hereinafter.

BRIEF DESCRIPTION OF THE SEVERAL VIEWS OF THE DRAWING

The accompanying drawings, which are incorporated
in and constitute a part of the specification,
illustrate embodiments of the invention, and together
25 with the generation description given above and the
detailed description of the embodiments given below,
serve to explain the principles of the invention.

FIG. 1 is a sectional view showing the first example of a magnetic recording medium according to the present invention;

FIG. 2 is a sectional view showing the second example of the magnetic recording medium according to the present invention;

FIG. 3 is a sectional view showing the third example of the magnetic recording medium according to the present invention;

FIG. 4 is a sectional view showing the fourth example of the magnetic recording medium according to the present invention;

FIG. 5 is a sectional view showing the fifth example of the magnetic recording medium according to the present invention;

FIG. 6 is a partially exploded perspective view showing an example of a magnetic recording/reproducing apparatus of the present invention;

FIG. 7 is a graph showing the relationship between the thickness of a second underlayer and d_{Mag} ;

FIG. 8 is a graph showing the relationship between the thickness of the second underlayer and $\Delta\theta_{50}$;

FIG. 9 is a graph showing the relationship between the thickness of the second underlayer and SNR;

FIG. 10 is a sectional view showing the sixth

example of the magnetic recording medium according to the present invention;

FIG. 11 is a graph showing the relationship between the thickness of a third underlayer and an average crystal grain size d_{Mag} ;

FIG. 12 is a graph showing the relationship between the thickness of the third underlayer and $\Delta\theta_{50}$;

FIG. 13 is a graph showing the relationship between the thickness of the third underlayer and SNR;

FIG. 14 is a sectional view showing the seventh example of the magnetic recording medium according to the present invention; and

FIG. 15 is a sectional view showing the eighth example of the magnetic recording medium according to the present invention.

DETAILED DESCRIPTION OF THE INVENTION

A magnetic recording medium of the present invention has a substrate, a soft magnetic layer formed on the substrate, a multilayered underlayer formed on the soft magnetic layer, and a perpendicular magnetic recording layer formed on the multilayered underlayer.

The perpendicular magnetic recording layer contains Co as a main component, and contains crystal grains having a hexagonal close-packed structure substantially aligned in a (0001) plane.

The multilayered underlayer includes a first underlayer containing Cu as a main component and containing crystal grains having a face-centered cubic lattice structure substantially aligned in a (111) plane, and a second underlayer formed on the first underlayer and containing Cu and nitrogen as main components.

A magnetic recording/reproducing apparatus of the present invention has the perpendicular magnetic recording medium described above and a recording/reproducing head.

Note that the term "main component" used in the present invention means a component constituting the largest content of components contained in the material, or a plurality of components whose constituency rank high.

FIG. 1 is a sectional view showing the first example of the magnetic recording medium according to the present invention.

As shown in FIG. 1, a magnetic recording medium 10 has a structure formed by sequentially stacking, on a substrate 1, a soft magnetic layer 2, a multilayered underlayer 7 including a first underlayer 3 and second underlayer 4, and a perpendicular magnetic recording layer 5.

The underlayer 3 contains Cu as a main component, and contains crystal grains having a face-centered

cubic lattice (fcc) structure substantially aligned in the (111) plane. The second underlayer 4 contains Cu and nitrogen as main components. The perpendicular magnetic recording layer 5 contains Co as a main component, and contains crystal grains having a hexagonal closest packed (hcp) structure substantially aligned in the (0001) plane.

A layer having a so-called granular structure in which the grain boundary region of a nonmagnetic material surrounds individual magnetic crystal grains can be used as the perpendicular magnetic recording layer of the perpendicular magnetic recording medium of the present invention. The nonmagnetic grain boundary region around the magnetic crystal grains in the perpendicular magnetic recording layer can reduce the exchange interaction between the magnetic crystal grains, thereby reducing the transition noise in the recording/reproduction characteristics.

An alloy material having the hcp structure substantially aligned in the (0001) plane and containing Co as a main component is used as the magnetic crystal grain material of the perpendicular magnetic recording layer. When the Co alloy crystal grains having the hcp structure are aligned in the (0001) plane, the axis of easy magnetization points in a direction perpendicular to the substrate surface. In one embodiment, it is possible to use, e.g.,

Co-Cr-based and Co-Pt-based alloy materials. Since these alloys have high crystal magnetic anisotropic energy, the thermal decay resistance often rises. Additive elements such as Ta, Cu, B, Cr, and Nd can be
5 added, if necessary, to these alloys in order to improve the magnetic characteristics.

In some embodiments, it is possible to use, e.g., CoCrPt, CoCrPtB, CoCrPtTa, CoCrPtNd, or CoCrPtCu as the magnetic crystal grain material of the
10 perpendicular magnetic recording layer.

A compound such as an oxide, nitride, or carbide can be used as the material forming the grain boundary region. These compounds easily precipitate because they hardly form solid solutions with the magnetic
15 crystal grain materials described above. Practical examples are SiO_x , TiO_x , CrO_x , AlO_x , MgO_x , TaO_x , YO_x , TiN_x , CrN_x , SiN_x , AlN_x , TaC_x , SiC_x , TiC_x , and TaC_x .

The material forming the grain boundary region can be either crystalline or amorphous.

20 In one embodiment, the material forming the grain boundary region can be added at a molecular number ratio of 1% to 50% (inclusive) to the magnetic crystal grain material. If the molecular number ratio is less than 1%, the magnetic isolation between the magnetic
25 crystal grains tends to become insufficient. If the molecular number ratio exceeds 50%, the (0001) alignment of the magnetic crystal grains tends to

deteriorate.

Whether the perpendicular magnetic recording layer has the granular structure can be checked by observing the perpendicular magnetic recording layer plane by using, e.g., a transmission electron microscope. It is also possible to identify the elements and evaluate the compositions in the crystal grain portion and grain boundary region by using energy dispersion X-ray spectroscopy (EDX) together.

The perpendicular magnetic recording layer can have a multilayered structure made up of two or more layers if necessary. In this case, at least one layer can be a magnetic layer containing, e.g., Co as a main component, and containing crystal grains having the hexagonal close-packed structure substantially aligned in the (0001) plane. In one embodiment, at least one layer forming the perpendicular magnetic recording layer can be a magnetic layer having the granular structure.

As the method of downsizing the crystal grains in the perpendicular magnetic recording layer, as described previously, it is possible to use the method of adding SiO₂ or the like to the perpendicular magnetic recording layer, and the method of downsizing the crystal grains in the underlayer by adding SiO₂ or the like to the underlayer, thereby further downsizing the crystal grains in the recording layer. At

present, however, the downsizing effects of these methods have reached their limits. In addition, when the underlayer crystal grains are downsized by these methods, the crystallinity, particularly, the
5 alignment of the underlayer crystal grains generally deteriorates. Consequently, the (0001) plane alignment of the perpendicular magnetic recording layer deteriorates, and this degrades the magnetic characteristics and recording/reproduction
10 characteristics.

To solve the above problem, the present inventors made extensive studies, and have found that when a thin layer which contains Cu and nitrogen as main components and in which Cu is modified is formed as a
15 second underlayer on a first underlayer containing Cu as a main component and having a face-centered cubic lattice structure substantially aligned in the (111) plane, it is possible to decrease the average crystal grain size in the perpendicular magnetic recording
20 layer, and improve the (0001) plane alignment of the magnetic crystal grains in the perpendicular magnetic recording layer.

The method of the present invention does not directly downsize the Cu crystal grains in the first
25 underlayer, and hence can improve the (0001) plane alignment of the magnetic crystal grains in the perpendicular magnetic recording layer without

deteriorating the crystallinity of the Cu underlayer. Accordingly, the recording/reproduction characteristics can well improve.

The alignment plane of the crystal grains in each layer can be evaluated by a so-called θ - 2θ method by using, e.g., a general X-ray diffraction apparatus (XRD). Also, the alignment dispersion can be evaluated by a full width at half maximum of a rocking curve, $\Delta\theta_{50}$.

In one embodiment, the (111) plane alignment of the Cu crystal grains sometimes improves when substrate heating is performed before and/or after the formation of the Cu underlayer.

An example of the method of forming the second underlayer containing Cu and nitrogen as main components on the first underlayer containing Cu as a main component is a method which forms a Cu underlayer, and exposes the surface of the Cu underlayer to a nitrogen plasma or nitrogen radicals to form a modified layer by doping nitrogen in Cu in the surface region of the Cu underlayer. It is also possible to perform so-called reverse sputtering which slightly sputters the Cu layer surface in a nitrogen atmosphere.

Whether the second underlayer containing Cu and nitrogen as main components exists in the surface region of the Cu underlayer can be checked by

performing EDX and medium section observation using,
e.g., a TEM together. This can also be checked by
analyzing means such as secondary ion mass
spectrometry (SIMS), Rutherford backscattering (RBS),
5 X-ray photoelectron spectroscopy (XPS), Auger electron
spectroscopy (AES), and a three-dimensional atom probe
method.

The thickness of the second underlayer can be
checked by observing the medium section by using,
10 e.g., a TEM. When the second underlayer containing Cu
and nitrogen as main components is formed, the
composition and crystallinity in the Cu underlayer as
the first underlayer are different from those in the
modified layer as the second underlayer. Since this
15 produces a contrast difference between the two layers
in a sectional TEM image, the thickness of the second
underlayer containing Cu and nitrogen as main
components can be evaluated.

Also, a so-called perpendicular double-layered
20 medium having a perpendicular magnetic recording layer
on a high-permeability soft magnetic layer is obtained
by forming the soft magnetic layer between the first
underlayer and substrate. In this perpendicular
double-layered medium, the soft magnetic layer
25 horizontally passes the recording magnetic field from
a magnetic head, e.g., a single pole head for
magnetizing the perpendicular magnetic recording layer

and returns the magnetic field to the magnetic head,
i.e., performs a part of the function of the magnetic
head. The soft magnetic layer can thus apply a steep
sufficient perpendicular magnetic field to the
5 magnetic field recording layer, thereby increasing the
recording/reproduction efficiency.

Examples of the material for use in this soft
magnetic layer are CoZrNb, FeSiAl, FeTaC, CoTaC, NiFe,
Fe, FeCoB, FeCoN, FeTaN, and CoIr.

10 The soft magnetic layer can be a multilayered
film including two or more layers. In this case, it
is possible to use layers different in material,
composition, and film thickness. It is also possible
to form a three-layered structure by sandwiching a
15 thin Ru layer between two soft magnetic layers.

Furthermore, a bias application layer such as a
longitudinal hard magnetic film or antiferromagnetic
film can be formed between the soft magnetic layer and
substrate.

20 FIG. 2 is a sectional view showing the second
example of the magnetic recording medium according to
the present invention.

As shown in FIG. 2, a magnetic recording medium
20 has the same structure as FIG. 1 except that a bias
25 application layer 8 is formed between a substrate 1
and soft magnetic layer 2.

The soft magnetic layer easily forms a magnetic

domain, and this magnetic domain generates spike
noise. Therefore, a magnetic field is applied in one
direction in the radial direction of the bias
application layer to apply a bias magnetic field to
5 the soft magnetic layer formed on the bias application
layer. It is also possible to give the bias
application layer a stacked structure to finely
disperse anisotropy, thereby preventing easy formation
of a large magnetic domain. Examples of the bias
10 application layer material are CoCrPt, CoCrPtB,
CoCrPtTa, CoCrPtTaNd, CoSm, CoPt, FePt, CoPtO,
CoPtCrO, CoPt-SiO₂, CoCrPt-SiO₂, CoCrPtO-SiO₂, FeMn,
IrMn, and PtMn.

Examples of the nonmagnetic substrate are a glass
15 substrate, an Al-based alloy substrate, an Si
single-crystal substrate having an oxidized surface,
ceramics, and plastic. In addition, similar effects
can be expected even when the surface of any of these
nonmagnetic substrates is plated with NiP alloy or the
20 like.

A protective layer can be formed on the
perpendicular magnetic recording layer.

FIG. 3 is a sectional view showing the third
example of the magnetic recording medium according to
25 the present invention.

As shown in FIG. 3, a magnetic recording medium
30 has the same structure as FIG. 1 except that a

protective layer 6 is formed on a perpendicular magnetic recording layer 5.

Examples of the protective layer are C, diamond-like carbon (DLC), SiN_x , SiO_x , and CN_x .

5 Each layer can be formed by vacuum vapor deposition, various sputtering methods, molecular beam epitaxy, ion beam vapor deposition, laser abrasion, and chemical vapor deposition.

10 In one embodiment, a second underlayer containing Cu and nitrogen as main components can have a thickness of 0.1 to 4 nm (inclusive). If the thickness is larger than 4 nm, the (0001) plane alignment of magnetic crystal grains in the perpendicular magnetic recording layer often
15 deteriorates. If the thickness is smaller than 0.1 nm, the effect of decreasing the grain size of the magnetic crystal grains often becomes insignificant.

20 In one embodiment, a first underlayer can have a thickness of 0.5 to 100 nm (inclusive). If the thickness is less than 0.5 nm, the (0001) alignment of the magnetic crystal grains often deteriorates. If the thickness exceeds 100 nm, the recording resolution of the R/W characteristics often decreases.

25 In one embodiment, Cu metal grains contained in the first underlayer can have an average grain size of 1 nm or more. When the average crystal grain size in the Cu underlayer is 1 nm or more, the (0001) plane

alignment of the magnetic crystal grains in the perpendicular magnetic recording layer can improve. In some embodiments, the average crystal grain size in the Cu underlayer can be 50 nm or more. In one
5 embodiment, the first underlayer can be a single-crystal film having no crystal grain boundary. If the average crystal grain size of Cu is less than 1 nm, the (111) alignment of the Cu crystal grains deteriorates. This often degrades the (0001) plane
10 alignment of the magnetic crystal grains in the perpendicular magnetic recording layer.

The average crystal grain size in each layer can be evaluated by, e.g., observing the plane of the layer by using a TEM. The present invention evaluates
15 the areas of 200 crystal grains from a planar TEM image, approximates the radii of these crystal grains to those of circles having the same areas as the crystal grains, and uses the average of the radii of these circles as the average crystal grain size.

20 A layer having a structure in which metal grains having grain sizes smaller than those of the Cu crystal grains in the first underlayer are isolated in the form of islands can also be formed as a third underlayer on the second underlayer containing Cu and
25 nitrogen as main components.

FIG. 4 is a sectional view showing the fourth example of the magnetic recording medium according to

the present invention.

As shown in FIG. 4, a magnetic recording medium 40 has the same structure as FIG. 1 except that a third underlayer 9 having an island-like isolated structure is formed between a second underlayer 4 and perpendicular magnetic recording layer 5.

In one embodiment, the third underlayer having the structure in which metal grains are isolated in the form of islands can further decrease the grain size of magnetic crystal grains in the perpendicular magnetic recording layer. When at least one third underlayer like this is inserted, the metal grains interfere with the growth of crystal grains in a layer formed on the third underlayer, so the crystal grain size can decrease.

An example of the method of forming the third underlayer as described above is a method of depositing a very thin layer of an appropriate metal element on the second underlayer containing Cu and nitrogen as main components. In one embodiment, examples of the metal element are Ag, Au, Pt, Pd, Ir, Co, and Fe. These metal elements can easily form an island-like isolated structure on the second underlayer containing Cu and nitrogen as main components.

Whether the third underlayer has the island-like isolated structure can be checked by, e.g., observing

the medium section by using a TEM.

In one embodiment, the average grain size in the third underlayer having the structure in which metal grains are isolated in the form of islands can be 0.1 to 1 nm (inclusive). If the average grain size is less than 0.1 nm, the effect of decreasing the grain size of the magnetic crystal grains in the perpendicular magnetic recording layer often becomes insignificant. If the average grain size exceeds 1 nm, the metal crystal grains often aggregate to form a continuous film, thereby increasing the grain size of the magnetic crystal grains in the perpendicular magnetic recording layer.

In one embodiment, the section observed using a TEM of the third underlayer having the structure in which metal grains are isolated in the form of islands can have a height of 0.1 to 1 nm (inclusive). The height of the third underlayer can be obtained by measuring, as heights, the diameters in the direction perpendicular to the film surface of island-like metal grains by sectional TEM observation, and averaging the measured diameters.

If the height of the third underlayer having the structure in which the metal grains are isolated in the form of islands is smaller than 0.1 nm, the effect of decreasing the grain size of the magnetic crystal grains in the perpendicular magnetic recording layer

often becomes insignificant. If the height is larger than 1 nm, the metal crystal grains often aggregate to form a continuous film, thereby increasing the grain size of the magnetic crystal grains in the perpendicular magnetic recording layer.

Furthermore, the crystal alignment of the perpendicular magnetic recording layer can be improved by inserting a nonmagnetic interlayer between the multilayered underlayer and perpendicular magnetic recording layer, e.g., between the third underlayer having the structure in which the metal grains are isolated in the form of islands and the perpendicular magnetic recording layer, or between the modified layer and perpendicular magnetic recording layer.

FIG. 5 is a sectional view showing the fifth example of the magnetic recording medium according to the present invention.

As shown in FIG. 5, a magnetic recording medium has the same structure as FIG. 4 except that a nonmagnetic interlayer 11 is formed between a third underlayer 9 having a structure in which metal grains are isolated in the form of islands and a perpendicular magnetic recording layer 5.

An example of the nonmagnetic crystal material of the nonmagnetic interlayer is Ru or Ti aligned in a (0001) plane. These elements well lattice-match with the magnetic crystal materials described above, and

can improve the crystal alignment of the perpendicular magnetic recording layer.

In one embodiment, a seed layer can be formed between a soft magnetic layer and Cu underlayer in order to improve the (111) plane alignment of crystal grains in the Cu underlayer. Examples of the material of this seed layer are Pt, Pd, Ni, NiFe, Co, Ti, and TiN. This alignment control underlayer need not be a layer in direct contact with the Cu underlayer.

FIG. 6 is a partially exploded perspective view showing an example of a magnetic recording/reproducing apparatus of the present invention.

A rigid magnetic disk 61 for information recording according to the present invention is fitted on a spindle 62 and rotated at a predetermined rotational speed by a spindle motor (not shown). A slider 63 carrying a recording head for accessing the magnetic disk 61 to record information and an MR head for reproducing information is attached to the distal end of a suspension 64 which is a thin leaf spring. The suspension 64 connects to one end of an arm 65 having, e.g., a bobbin for holding a driving coil (not shown).

A voice coil motor 66 as a kind of a linear motor is attached to the other end of the arm 65. The voice coil motor 66 includes the driving coil (not shown) wound around the bobbin of the arm 65, and a magnetic

circuit having a permanent magnet and counter yoke which oppose each other to sandwich the driving coil between them.

5 Ball bearings (not shown) formed in two, upper and lower portions of a fixed shaft 67 hold the arm 65, and the voice coil motor 66 pivots the arm 65. That is, the voice coil motor 66 controls the position of the slider 63 on the magnetic disk 61. Reference numeral 68 in FIG. 6 denotes a lid.

10 The present invention will be described in more detail below by way of its examples.

Example 1

A 2.5-inch nonmagnetic glass substrate (TS-10SX manufactured by ohara) having the shape of a hard disk
15 was prepared.

This substrate was loaded into a vacuum chamber of a c-3010 sputtering apparatus manufactured by anelva.

20 After the vacuum chamber of the sputtering apparatus was evacuated to 1×10^{-5} Pa or less, a 100-nm-thick $\text{Co}_{90}\text{Zr}_5\text{Nb}_5$ film was formed as a soft magnetic layer, and the substrate was heated to 180°C by using an infrared lamp heater.

25 Then, a 15-nm thick Cu film was formed as a first underlayer on the soft magnetic layer.

After the formation of this Cu film, the Cu surface was reversely sputtered, and nitrogen was

doped into the surface region of the Cu layer to form a second underlayer. The reverse sputtering to the Cu surface was performed by applying 70-W RF power to the Cu surface for 5 sec in a 3-Pa nitrogen ambient.

5 After that, a 15-nm-thick (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂ film was formed as a perpendicular magnetic recording layer.

Subsequently, a 5-nm-thick C film was formed as a protective layer.

10 The surface of the protective layer was then coated with a 13-Å-thick perfluoropolyether (PFPE) lubricating agent to form a lubricating layer by dipping, thereby obtaining a magnetic recording medium.

15 The obtained magnetic recording medium had the same structure as FIG. 3 although FIG. 3 shows no lubricating layer.

20 Note that the Co₉₀Zr₅Nb₅, Cu, (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂, and C films were formed by DC sputtering at Ar pressures of 0.7, 0.7, 5, and 0.7 Pa by using Co₉₀Zr₅Nb₅, Cu, (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂, and C targets, respectively. The input power to each target was 1,000 W.

25 The fine structure of the obtained magnetic recording medium and an average crystal grain size dMag of the perpendicular magnetic recording layer were observed and measured on the plane and section by

using a transmission electron microscope (TEM) at an acceleration voltage of 400 kV.

The distributions of Cu and nitrogen atoms in the direction of depth of each magnetic recording medium were measured by secondary ion mass spectrometry (SIMS) using Cs^+ ions.

The crystal alignment plane of each layer and an alignment dispersion $\Delta\theta_{50}$ in the (0001) plane of the crystal grains in the perpendicular magnetic recording layer were measured by a θ - 2θ method and rocking curve, respectively, by using an X-ray diffraction apparatus X'pert-MRD manufactured by Philips of the Netherlands.

The R/W characteristic of the magnetic recording medium was checked by using a spin stand. A combination of a single pole head having a recording track width of 0.3 μm and an MR head having a reproduction track width of 0.2 μm was used as a magnetic head.

The measurement was performed in a fixed radial position of 20 mm while the disk was rotated at 4,200 rpm.

As a medium SNR, the value of a signal-to-noise ratio (SNR_m) (S is the output at a linear recording density of 119 kfc/i, and N_m is the value of rms [root mean square] at 716 kfc/i) of a differential waveform having passed through a differentiating circuit was

measured.

Table 1 below shows the average crystal grain size dMag of the perpendicular magnetic recording layer, the alignment dispersion $\Delta\theta_{50}$ in the (0001) plane of the perpendicular magnetic recording layer, and the R/W characteristic of the perpendicular magnetic recording medium.

Comparative Example 1

Following the same procedure as in Example 1, a soft magnetic layer was formed on a 2.5-inch nonmagnetic glass substrate having the shape of a hard disk.

A 10-nm thick Ta film, 5-nm-thick Pt film, and 20-nm thick Ru film were sequentially formed on the soft magnetic layer. Then, a 15-nm-thick (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂ film was formed as a perpendicular magnetic recording layer, and a 5-nm-thick C protective layer was formed. After that, the surface was coated with a lubricating agent in the same manner as in Example 1.

Note that the Co₉₀Zr₅Nb₅, Ta, Pt, Ru, (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂, and C films were formed by DC sputtering at Ar pressures of 0.7, 0.7, 0.7, 5, 5, and 0.7 Pa by using Co₉₀Zr₅Nb₅, Ta, Pt, Ru, (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂, and C targets, respectively. The input power to each target was 1,000 W.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 2

A perpendicular magnetic recording medium was obtained following the same procedures as in Comparative Example 1 except that Ru was changed to Ru-10 mol% SiO₂.

The Ru-10 mol% SiO₂ film was formed by DC sputtering at an input power of 1,000 W and an Ar pressure of 5 Pa by using an Ru-10 mol% SiO₂ target.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 3

A perpendicular magnetic recording medium was manufactured following the same procedures as in Example 1 except that a Cu underlayer as a first underlayer was changed to a 15-nm-thick Ru underlayer.

After the Ru film was formed on a soft magnetic layer, reverse sputtering, perpendicular magnetic recording layer formation, protective layer formation, and lubricating agent coating were sequentially

performed to obtain a magnetic recording medium.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 4

A magnetic recording medium was manufactured following the same procedures as in Example 1 except that no reverse sputtering was performed on the Cu surface of a first underlayer.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were measured.

The inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the crystal grains in the magnetic recording layers of Example 1 and Comparative Examples 1 to 4. Consequently, the crystal grains in the magnetic recording layers had a hexagonal close-packed structure.

Also, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and

sectional TEM images of the Cu underlayers of Example 1 and Comparative Example 4. Consequently, the Cu crystal grains in the Cu underlayers had a face-centered cubic lattice structure.

5 Evaluations of Results by X-Ray Diffraction Apparatus (XRD)

The magnetic crystal grains in the magnetic recording layer of any of Example 1 and Comparative Examples 1 to 4 had the hcp structure and were aligned
10 in the (0001) plane, i.e., perpendicularly aligned.

The Cu crystal grains in the Cu underlayer of each of Example 1 and Comparative Example 4 had the fcc structure and were aligned in the (111) plane.

Results of Planar TEM Observation

15 The perpendicular magnetic recording layer of the perpendicular magnetic recording medium of any of Example 1 and Comparative Examples 1 to 4 had a granular structure.

The results of sectional TEM observation
20 indicates that a 1-nm thick second underlayer having a different contrast formed on the Cu underlayer of the medium of Example 1. By contrast, no such second underlayer was found in Comparative Examples 1 to 4.

Results of SIMS

25 In Example 1, a layer containing Cu and N as main components formed between the perpendicular magnetic recording layer and Cu underlayer. No such layer was

found in the media of Comparative Examples 1 to 4.

Table 1 shows the average crystal grain size dMag, $\Delta\theta_{50}$, and SNR of the perpendicular magnetic recording layer of each magnetic recording medium.

5

Table 1

	dMag (nm)	$\Delta\theta_{50} (^{\circ})$	SNR (dB)
Example 1	7.9	5.0	17.0
Comparative Example 1	9.1	6.1	14.3
Comparative Example 2	8.6	7.0	14.0
Comparative Example 3	9.5	6.0	13.6
Comparative Example 4	10.0	5.1	13.1

10 A comparison of Example 1 with Comparative Examples 1 and 2 shows that the perpendicular magnetic recording medium of the present invention was superior to the conventional media in any of decrease in the average crystal grain size dMag, decrease in the alignment dispersion $\Delta\theta_{50}$, and increase in the SNR of the perpendicular magnetic recording layer.

15 A comparison of Example 1 with Comparative Example 3 shows that when the Cu underlayer was replaced with the Ru underlayer, neither the effect of noticeably decreasing the average crystal grain size dMag nor the remarkable increase in SNR was obtained
20 unlike in the present invention.

A comparison of Example 1 with Comparative

Examples 4 and 5 demonstrates that when no second underlayer containing Cu and N as main components was formed on the Cu underlayer, neither the effect of conspicuously decreasing the average crystal grain size dMag nor the notable increase in SNR was obtained unlike in the present invention.

Example 2

Media were manufactured following the same procedures as in Example 1 except that the reverse sputtering time was changed from 1 to 120 sec. Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

The inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the crystal grains in magnetic recording layers. Consequently, the crystal grains in the magnetic recording layers had a hexagonal close-packed structure.

Also, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of Cu underlayers. Consequently, the Cu crystal grains in the Cu underlayers had a

face-centered cubic lattice structure.

Results of XRD Measurements

5 The magnetic crystal grains in the magnetic recording layer of each perpendicular magnetic recording medium had the hcp structure and were aligned in the (0001) plane.

 The Cu crystal grains in the Cu underlayer of each perpendicular magnetic recording medium had the fcc structure and were aligned in the (111) plane.

10 Results of Planar TEM Observation

 The perpendicular magnetic recording layer of each perpendicular magnetic recording medium had a granular structure.

Results of Sectional TEM Observation

15 The thickness of a second underlayer on the Cu underlayer changed from 0 to 14 nm (inclusive) in accordance with the reverse sputtering time.

Results of SIMS

20 A layer containing Cu and N as main components was formed between the perpendicular magnetic recording layer and Cu underlayer.

 FIGS. 7, 8, and 9 are graphs respectively showing the relationship between the thickness of the second underlayer containing Cu and N as main components and the dMag, the relationship between the thickness of the second underlayer containing Cu and N as main components and the $\Delta\theta_{50}$, and the relationship between

25

the thickness of the second underlayer containing Cu and N as main components and the SNR.

As shown in FIGS. 7 to 9, the SNR noticeably increased when the thickness of the second underlayer containing Cu and N as main components was 0.1 to 4 nm (inclusive).

Example 3

A perpendicular magnetic recording medium was obtained following the same procedures as in Example 1 except that an Ag film was formed as a third underlayer on a second underlayer, and a perpendicular magnetic recording layer was formed after that in the same manner as in Example 1.

FIG. 10 is a sectional view schematically showing the structure of the obtained perpendicular magnetic recording medium.

As shown in FIG. 10, a perpendicular magnetic recording medium 60 had the same structure as FIG. 4 except that a protective layer 6 and a lubricating layer (not shown) were formed on a magnetic recording layer 5.

Note that the Ag third underlayer was formed by DC sputtering by using an Ag target at a film formation rate of 0.05 nm/s as a value for a continuous film for a film formation time of 4 sec.

In addition, media using Au, Pt, Pd, Ir, Co, and Fe instead of Ag as third underlayers were

manufactured.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 5

A perpendicular magnetic recording medium was obtained following the same procedures as in Comparative Example 1 except that an Ag film was formed as a third underlayer on an Ru layer in the same manner as in Example 3, and a magnetic recording layer was formed after that.

Media using Au, Pt, Pd, Ir, Co, and Fe instead of Ag as third underlayers were also manufactured.

Furthermore, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 6

A perpendicular magnetic recording medium was obtained following the same procedures as in Comparative Example 2 except that an Ag film was formed as a third underlayer on an Ru-10 mol% SiO₂ layer in the same manner as in Example 3, and a magnetic recording layer was formed after that.

Media using Au, Pt, Pd, Ir, Co, and Fe instead of Ag as third underlayers were also manufactured.

Furthermore, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and
5 X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 7

A perpendicular magnetic recording medium was
10 obtained following the same procedures as in Comparative Example 3 except that an Ag film was formed as a third underlayer on an Ru layer in the same manner as in Example 3, and a magnetic recording layer was formed after that.

15 Media using Au, Pt, Pd, Ir, Co, and Fe instead of Ag as third underlayers were also manufactured.

Furthermore, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and
20 X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 8

A perpendicular magnetic recording medium was obtained following the same procedures as in
25 Comparative Example 4 except that an Ag film was formed as a third underlayer on a Cu layer in the same manner as in Example 3, and a magnetic recording layer

was formed after that.

Media using Au, Pt, Pd, Ir, Co, and Fe instead of Ag as third underlayers were also manufactured.

Furthermore, following the same procedures as in
5 Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

The inter-lattice distance was evaluated from
10 diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the crystal grains in the magnetic recording layers. Consequently, the crystal grains in the magnetic recording layers had a hexagonal close-packed
15 structure.

Also, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the Cu underlayers.
20 Consequently, the Cu crystal grains in the Cu underlayers had a face-centered cubic lattice structure.

Results of XRD Measurements

The magnetic crystal grains in the magnetic
25 recording layer of each perpendicular magnetic recording medium had the hcp structure and were aligned in the (0001) plane.

The Cu crystal grains in the Cu underlayer of each of Example 3 and Comparative Example 8 had the fcc structure and were aligned in the (111) plane.

Results of Planar TEM Observation

5 The perpendicular magnetic recording layer of each perpendicular magnetic recording medium had a granular structure.

 The results of sectional TEM observation indicate that a 1-nm-thick second underlayer having a different contrast formed on the Cu underlayer of the medium of
10 Example 3. No such second underlayer was found in the other media.

Results of SIMS

 A layer containing Cu and N as main components
15 formed between the recording layer and Cu underlayer of the medium of Example 3. No such layer was found in the other media.

Results of Sectional TEM Observation

 A 0.3-nm-thick layer made of Ag grains isolated
20 in the form of islands formed between the second underlayer containing Cu and N as main components and the perpendicular magnetic recording layer of the medium of Example 3. The results of planar TEM observation indicate that the average crystal grain
25 size in the Cu underlayer was about 12 nm. Since the average grain size of the Ag grains was smaller than that in the Cu underlayer, this layer was a third

underlayer having a structure in which metal grains were isolated in the form of islands. Similar structures were found in the media in which the metal grains were Au, Pt, Pd, Ir, Co, and Fe. On the other hand, in the media of Comparative Examples 5, 6, 7, and 8, the third underlayer had a continuous film-like structure rather than an island-like isolated structure.

Table 2 below shows the average crystal grain size dMag, $\Delta\theta_{50}$, and SNR of the perpendicular magnetic recording layer of each magnetic recording medium.

Table 2

	Third undercoating	dMag (nm)	$\Delta\theta_{50} (^{\circ})$	SNR (dB)
Example 3	Ag	6.9	5	18
Example 3	Au	7.3	5.3	17.7
Example 3	Pt	7.4	4.7	17.7
Example 3	Pd	7.4	4.8	17.6
Example 3	Ir	7.4	4.7	17.3
Example 3	Co	7.5	4.8	17.5
Example 3	Fe	7.1	5.4	17.3
Comparative Example 5	Ag	10.1	7.0	13.5
Comparative Example 6	Ag	9.7	8.0	13.0
Comparative Example 7	Ag	10.1	6.3	12.4
Comparative Example 8	Ag	10.5	5.3	12.0

A comparison of Example 3 with Example 1 shows

that the average crystal grain size d_{Mag} , $\Delta\theta_{50}$, and SNR of the perpendicular magnetic recording layer improved when the third underlayer having the structure in which the metal grains were isolated in the form of islands formed on the second underlayer containing Cu and N as main components.

A comparison of Example 3 with Comparative Examples 5 and 6 shows that no third underlayer having the structure in which the metal grains were isolated in the form of islands formed on the Ru or Ru-SiO₂ underlayer, so the average crystal grain size d_{Mag} , $\Delta\theta_{50}$, and SNR did not remarkably improve unlike in the present invention.

A comparison of Example 3 with Comparative Example 7 demonstrates that when the Ru underlayer was used instead of the Cu underlayer, neither the second underlayer containing Cu and N as main components nor the third underlayer having the structure in which the metal grains were isolated in the form of islands formed, so the d_{Mag} and SNR did not noticeably improve.

A comparison of Example 3 with Comparative Example 8 indicates that when no second underlayer containing Cu and N as main components formed on the Cu underlayer, no third underlayer having the structure in which the metal grains were isolated in the form of islands formed, so the d_{Mag} and SNR did

not notably improve.

Example 4

Various perpendicular magnetic recording media were obtained following the same procedures as in
5 Example 3 except that a third underlayer was deposited at a film formation rate of 0.05 nm/s as a value for a continuous film while the film formation time was changed from 0.5 to 25 sec (inclusive).

Also, following the same procedures as in
10 Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

The inter-lattice distance was evaluated from
15 diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the crystal grains in perpendicular magnetic recording layers. Consequently, the crystal grains in the magnetic recording layers had a hexagonal close-
20 packed structure.

Also, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of Cu underlayers. Consequently,
25 the Cu crystal grains in the Cu underlayers had a face-centered cubic lattice structure.

Results of XRD Measurements

The magnetic crystal grains in the magnetic recording layer of each perpendicular magnetic recording medium had the hcp structure and were aligned in the (0001) plane.

The Cu crystal grains in the Cu underlayer of each perpendicular magnetic recording medium had the fcc structure and were aligned in the (111) plane.

Results of Planar TEM Observation

The perpendicular magnetic recording layer of each perpendicular magnetic recording medium had a granular structure.

Results of Sectional TEM Observation

A 1-nm-thick second underlayer having a different contrast formed on the Cu underlayer of each medium.

Results of SIMS

A layer containing Cu and N as main components formed on the Cu underlayer of each medium.

Results of Sectional TEM Observation

In a medium in which the third underlayer material was Ag, an Ag third underlayer isolated in the form of islands formed on the second underlayer containing Cu and N as main components.

Similar structures were found in media in which the third underlayer materials were Au, Pt, Pd, Ir, Co, and Fe.

FIGS. 11, 12, and 13 are graphs respectively

showing the relationship between the thickness of the Ag third underlayer and the average crystal grain size dMag, the relationship between the thickness of the Ag third underlayer and the $\Delta\theta_{50}$, and the relationship between the thickness of the Ag third underlayer and the SNR.

In one embodiment, as shown in FIGS. 11 to 13, the dMag and SNR conspicuously improved when the thickness of the Ag third underlayer was 0.1 to 1 nm (inclusive). Similar tendencies were found in the media in which the third underlayers were made of Au, Pt, Pd, Ir, Co, and Fe.

Example 5

A perpendicular magnetic recording medium was obtained following the same procedures as in Example 1 except that a 20-nm-thick Ru film was formed as a nonmagnetic interlayer on a second underlayer, and a perpendicular magnetic recording layer was formed after that in the same manner as in Example 1.

FIG. 14 is a sectional view schematically showing the structure of the obtained perpendicular magnetic recording medium.

As shown in FIG. 14, a perpendicular magnetic recording medium 70 had the same structure as FIG. 3 except that a nonmagnetic interlayer 11 was formed between a second underlayer 4 and magnetic recording layer 5, and a lubricating layer (not shown) was

formed on a protective layer 6.

Note that the Ru interlayer was formed by DC sputtering by using an Ru target. The input power to the target was 1,000 W, and the Ar pressure during
5 sputtering was 5 Pa. A medium using Ti instead of Ru as an interlayer was similarly manufactured.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic
10 test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 9

A perpendicular magnetic recording medium was obtained following the same procedures as in Example 5
15 except that a 20-nm-thick Cr film was formed instead of an Ru film as an interlayer.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic
20 test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

The inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM
25 images of the crystal grains in the perpendicular magnetic recording layers. Consequently, the crystal grains in the magnetic recording layers had a

hexagonal close-packed structure.

Also, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the Cu underlayers. Consequently, the Cu crystal grains in the Cu underlayers had a face-centered cubic lattice structure.

Furthermore, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the Ru, Ti, and Cr interlayers. Consequently, the Ru and Ti crystal grains in the Ru and Ti interlayers had a hexagonal close-packed structure. On the other hand, the Cr crystal grains in the Cr interlayer had a body-centered cubic structure.

Results of XRD Measurements

The magnetic crystal grains in the perpendicular magnetic recording layer of the perpendicular magnetic recording medium of Example 5 had the hcp structure and were aligned in the (0001) plane. On the other hand, the magnetic crystal grains in the perpendicular magnetic recording layer of the perpendicular magnetic recording medium of Comparative Example 9 had the hcp structure but were not aligned in the (0001) plane.

The Ru and Ti crystal grains in the perpendicular

magnetic recording medium of Example 5 had the hcp structure and were aligned in the (0001) plane.

The Cu crystal grains in the Cu underlayer of the perpendicular magnetic recording medium of Example 5 had the fcc structure and were aligned in the (111) plane.

Results of Planar TEM Observation

The perpendicular magnetic recording layer of each perpendicular magnetic recording medium had a granular structure.

The results of sectional TEM observation indicate that a 1-nm-thick second underlayer having a different contrast formed on the Cu underlayer of each medium.

The results of SIMS show that a layer containing Cu and N as main components formed on the Cu underlayer of each medium.

Table 3 below shows the average crystal grain size dMag, $\Delta\theta_{50}$, and SNR of the perpendicular magnetic recording layer of each magnetic recording medium.

Table 3

	Interlayer	dMag(nm)	$\Delta\theta_{50}(^{\circ})$	SNR(dB)
Example 5	Ru	7.9	3.6	18.5
Example 5	Ti	7.7	3.8	18.4
Comparative Example 9	Cr	11.2	-	10.0

A comparison of Example 5 with Example 1 shows that the $\Delta\theta_{50}$ and SNR remarkably improved when the Ru and Ti interlayers formed on the second underlayer

containing Cu and N as main components.

5 A comparison of Example 5 with Comparative Example 9 shows that the perpendicular magnetic recording layer was not aligned in the (0001) plane when the Cr interlayer formed on the second underlayer containing Cu and N as main components.

Example 6

10 Various perpendicular magnetic recording media were obtained following the same procedures as in Example 3 except that an Ru interlayer similar to Example 5 was formed between a third underlayer formed into islands and a perpendicular magnetic recording layer. In addition, media using Ti instead of Ru as an interlayer were manufactured.

15 Each obtained perpendicular magnetic recording medium had the same structure as FIG. 4 except that a protective layer 6 and a lubricating layer (not shown) were formed on a magnetic recording layer 5.

20 Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

Comparative Example 10

25 A perpendicular magnetic recording medium was obtained following the same procedures as in Example 6 except that a 20-nm-thick Cr film was formed instead

of an Ru film as an interlayer.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

The inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the crystal grains in the magnetic recording layers. Consequently, the crystal grains in the magnetic recording layers had a hexagonal close-packed structure.

Also, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of Cu underlayers. Consequently, the Cu crystal grains in the Cu underlayers had a face-centered cubic lattice structure.

Furthermore, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the Ru, Ti, and Cr interlayers. Consequently, the Ru and Ti crystal grains in the Ru and Ti interlayers had a hexagonal close-packed structure. On the other hand, the Cr crystal grains in the Cr interlayer had a

body-centered cubic structure.

Results of XRD Evaluations

The magnetic crystal grains in the perpendicular magnetic recording layer of each perpendicular magnetic recording medium of Example 6 had the hcp structure and were aligned in the (0001) plane. However, the magnetic crystal grains in Comparative Example 10 had the hcp structure but were not aligned in the (0001) plane.

The Ru and Ti nonmagnetic crystal grains in each perpendicular magnetic recording medium had the hcp structure and were aligned in the (0001) plane. However, the Cr crystal grains in Comparative Example 10 had no hcp structure and were not aligned in the (0001) plane.

The Cu crystal grains in the Cu underlayer of each perpendicular magnetic recording medium had the fcc structure and were aligned in the (111) plane.

Results of Planar TEM Observation

The perpendicular magnetic recording layer of each perpendicular magnetic recording medium had a granular structure.

Results of Sectional TEM Observation

A 1-nm-thick second underlayer having a different contrast formed on the Cu underlayer of each medium.

Results of SIMS

A layer containing Cu and N as main components

formed on the Cu underlayer of each medium.

Results of Sectional TEM Observation

A third underlayer isolated in the form of islands formed on the second underlayer containing Cu and N as main components of each medium.

Table 4 below shows the average crystal grain size d_{Mag} , $\Delta\theta_{50}$, and SNR of the perpendicular magnetic recording layer of each obtained magnetic recording medium.

Table 4

	Third undercoating	Interlayer	d_{Mag} (nm)	$\Delta\theta_{50}$ (°)	SNR (dB)
Example 6	Ag	Ru	6.9	4.5	19.5
Example 6	Au	Ru	7.0	4.2	19.0
Example 6	Pt	Ru	7.2	4.1	19.3
Example 6	Pd	Ru	7.2	4.1	19.2
Example 6	Ir	Ru	7.1	4.2	19.3
Example 6	Co	Ru	7.2	4.1	19.4
Example 6	Fe	Ru	6.9	4.5	18.8
Example 6	Ag	Ti	6.8	4.6	19.4
Example 6	Au	Ti	6.9	4.4	18.9
Example 6	Pt	Ti	7.0	4.3	19.0
Example 6	Pd	Ti	7.0	4.3	19.0
Example 6	Ir	Ti	7.0	4.3	19.1
Example 6	Co	Ti	6.9	4.2	19.2
Example 6	Fe	Ti	7.0	4.7	18.7

A comparison of Example 6 with Example 3 shows that the $\Delta\theta_{50}$ and SNR improved when the Ru or Ti interlayer formed on the third underlayer having the structure in which the metal grains were isolated in

the form of islands.

A comparison of Example 6 with Example 5 shows that the average crystal grain size dMag and SNR further improved when the third underlayer having the structure in which the metal grains were isolated in the form of islands formed between the second underlayer containing Cu and N as main components and the interlayer.

In Comparative Example 10, unlike in Example 6, the perpendicular magnetic recording layer was not aligned in the (0001) plane because the Cr interlayer formed on the third underlayer having the structure in which the metal grains were isolated in the form of islands.

Example 7

Perpendicular magnetic recording media were obtained following the same procedures as in Example 6 except that a 3-nm-thick Pd layer was formed as a seed layer between a substrate and soft magnetic layer, and Ru was used as an interlayer.

The Pd seed layer was formed by DC sputtering by using a Pd target. The input power to the target was 1,000 W, and the Ar pressure during sputtering was 0.7 Pa. Similarly, media using Pt, Ni, NiFe, Co, Ti, and TiN instead of Pd as seed layers were manufactured.

FIG. 15 is a sectional view schematically showing

the structure of the obtained perpendicular magnetic recording medium.

As shown in FIG. 15, a perpendicular magnetic recording medium 80 had the same structure as FIG. 5 except that a seed layer 8 was formed between a substrate 1 and soft magnetic layer 2, and a protective layer 6 and a lubricating layer (not shown) were formed on a magnetic recording layer 5.

Also, following the same procedures as in Example 1, the measurements using a TEM, SIMS, and X-ray diffraction apparatus and the R/W characteristic test were performed, and the dMag, $\Delta\theta_{50}$, and medium SNR were obtained.

The inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of the crystal grains in the magnetic recording layers. Consequently, the crystal grains in the magnetic recording layers had a hexagonal close-packed structure.

Also, the inter-lattice distance was evaluated from diffraction spots obtained from selected-area electron beam diffraction patterns in planar and sectional TEM images of Cu underlayers. Consequently, the Cu crystal grains in the Cu underlayers had a face-centered cubic lattice structure.

Furthermore, the inter-lattice distance was

evaluated from diffraction spots obtained from
selected-area electron beam diffraction patterns in
planar and sectional TEM images of the Ru interlayer.
Consequently, the Ru crystal grains in the Ru
interlayer had a hexagonal close-packed structure.

Results of XRD Measurements

The magnetic crystal grains in the perpendicular
magnetic recording layer of each perpendicular
magnetic recording medium had the hcp structure and
were aligned in the (0001) plane.

The Ru crystal grains in each perpendicular
magnetic recording medium had the hcp structure and
were aligned in the (0001) plane.

The Cu crystal grains in the Cu underlayer of
each perpendicular magnetic recording medium had the
fcc structure and were aligned in the (111) plane.

Results of Planar TEM Observation

The perpendicular magnetic recording layer of
each perpendicular magnetic recording medium had a
granular structure.

Results of Sectional TEM Observation

A 1-nm-thick second underlayer having a different
contrast formed on the Cu underlayer of each medium.

Also, a third underlayer isolated in the form of
islands formed on the second underlayer containing Cu
and N as main components in each medium.

Results of SIMS

A layer containing Cu and N as main components formed on the Cu underlayer of each medium.

Table 5 below shows the average crystal grain size dMag, $\Delta\theta_{50}$, and SNR of the perpendicular magnetic recording layer of each perpendicular magnetic recording medium using the Ag third underlayer and Ru interlayer obtained as described above.

Table 5

	Seed layer	Third undercoating	Interlayer	dMag (nm)	$\Delta\theta_{50}$ (°)	SNR (dB)
Example 7	Pd	Ag	Ru	6.7	3.1	20.5
Example 7	Pt	Ag	Ru	6.6	3.1	20.3
Example 7	Ni	Ag	Ru	6.5	3.4	20.1
Example 7	NiFe	Ag	Ru	6.7	3.3	20.8
Example 7	Co	Ag	Ru	6.4	3.5	20.1
Example 7	Ti	Ag	Ru	6.7	3.0	20.2
Example 7	TiN	Ag	Ru	6.5	3.4	20.3

A comparison of Example 7 with Example 6 shows that the $\Delta\theta_{50}$ and SNR further improved when the Pd, Pt, Ni, NiFe, Co, Ti, or TiN seed layer was formed on the Cu underlayer. Similar effects were found in the medium using Au, Pt, Pd, Ir, Co, or Fe as the third underlayer having the structure in which the metal grains were isolated in the form of islands, and using Ti as the interlayer.

Example 8

Perpendicular magnetic recording media were obtained following the same procedures as in Example 7 except that (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% TiO₂,

(Co₇₈-Cr₁₀-Pt₁₂)-10 mol% Cr₂O₃, (Co₇₈-Cr₁₀-Pt₁₂)-
10 mol% Al₂O₃, (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% Ta₂O₅,
(Co₇₈-Cr₁₀-Pt₁₂)-10 mol% Y₂O₃, and
(Co₇₈-Cr₁₀-Pt₁₂)-10 mol% MgO were used instead of
5 (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂ as perpendicular
magnetic recording layers.

The inter-lattice distance was evaluated from
diffraction spots obtained from selected-area electron
beam diffraction patterns in planar and sectional TEM
10 images of the crystal grains in the perpendicular
magnetic recording layers. Consequently, the crystal
grains in the magnetic recording layers had a
hexagonal close-packed structure.

Also, the inter-lattice distance was evaluated
15 from diffraction spots obtained from selected-area
electron beam diffraction patterns in planar and
sectional TEM images of Cu underlayers. Consequently,
the Cu crystal grains in the Cu underlayers had a
face-centered cubic lattice structure.

20 Furthermore, the inter-lattice distance was
evaluated from diffraction spots obtained from
selected-area electron beam diffraction patterns in
planar and sectional TEM images of Ru interlayers.
Consequently, the Ru crystal grains in the Ru
25 interlayers had a hexagonal close-packed structure.

Results of XRD Measurements

The magnetic crystal grains in the perpendicular

magnetic recording layer of each perpendicular magnetic recording medium had the hcp structure and were aligned in the (0001) plane.

5 The Ru crystal grains in each perpendicular magnetic recording medium had the hcp structure and were aligned in the (0001) plane.

 The Cu crystal grains in the Cu underlayer of each perpendicular magnetic recording medium had the fcc structure and were aligned in the (111) plane.

10 Results of Planar TEM Observation

 The perpendicular magnetic recording layer of each perpendicular magnetic recording medium had a granular structure.

 Results of Sectional TEM Observation

15 A 1-nm-thick second underlayer having a different contrast formed on the Cu underlayer of each medium. Also, a third underlayer isolated in the form of islands formed on a second underlayer containing Cu and N as main components.

20 Results of SIMS

 A layer containing Cu and N as main components formed on the Cu underlayer of each medium.

 Table 6 below shows the average crystal grain size d_{Mag} , $\Delta\theta_{50}$, and SNR of the perpendicular magnetic recording layer of each magnetic recording medium.

25

Table 6

	Perpendicular magnetic recording layer	dMag (nm)	$\Delta\theta_{50}$ (°)	SNR (dB)
Example 8	(Co ₇₈ Cr ₁₀ Pt ₁₂)-10% TiO ₂	5.9	3.6	20.4
Example 8	(Co ₇₈ Cr ₁₀ Pt ₁₂)-10% Cr ₂ O ₃	6.5	3.3	20.7
Example 8	(Co ₇₈ Cr ₁₀ Pt ₁₂)-10% Al ₂ O ₃	5.9	4.2	20.0
Example 8	(Co ₇₈ Cr ₁₀ Pt ₁₂)-10% Ta ₂ O ₅	5.7	4.4	19.9
Example 8	(Co ₇₈ Cr ₁₀ Pt ₁₂)-10% Y ₂ O ₃	5.8	4.4	19.8
Example 8	(Co ₇₈ Cr ₁₀ Pt ₁₂)-10% MgO	5.7	4.5	19.5

Even when (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% TiO₂,
 5 (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% Cr₂O₃, (Co₇₈-Cr₁₀-Pt₁₂)-
 10 mol% Al₂O₃, (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% Ta₂O₅,
 (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% Y₂O₃, and
 (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% MgO were used instead of
 (Co₇₈-Cr₁₀-Pt₁₂)-10 mol% SiO₂ as perpendicular
 10 magnetic recording layers, the average crystal grain
 size dMag, $\Delta\theta_{50}$, and SNR noticeably improved compared
 to the conventional media. Similar effects were also
 found in media using Pd, Pt, Ni, Co, Ti, and TiN as
 seed layers, Au, Pt, Pd, Ir, Co, and Fe as third
 15 underlayers having the structure in which metal grains
 were isolated in the form of islands, and Ti as an
 interlayer.

Additional advantages and modifications will
 readily occur to those skilled in the art. Therefore,
 20 the invention in its broader aspects is not limited to
 the specific details and representative embodiments
 shown and described herein. Accordingly, various

modifications may be made without departing from the spirit or scope of the general inventive concept as defined by the appended claims and their equivalents.

WHAT IS CLAIMED IS:

1. A magnetic recording medium comprising:
a substrate;
a soft magnetic layer formed on the substrate;
5 a multilayered underlayer comprising a first underlayer formed on the soft magnetic layer, containing copper as a main component, and containing crystal grains with a face-centered cubic lattice structure substantially aligned in a (111) plane, and
10 a second underlayer formed on the first underlayer and containing copper and nitrogen as main components; and
a perpendicular magnetic recording layer formed on the multilayered underlayer, containing cobalt as a main component, and containing crystal grains with a
15 hexagonal close-packed structure substantially aligned in a (0001) plane.
2. A medium according to claim 1, wherein a thickness of the second underlayer is 0.1 to 4 nm (inclusive).
- 20 3. A medium according to claim 1, wherein the multilayered underlayer further comprises an island-like third underlayer formed on the second underlayer.
- 25 4. A medium according to claim 3, wherein the third underlayer contains metal crystal grains containing at least one metal selected from the group consisting of silver, gold, platinum, palladium,

iridium, cobalt, and iron, and an average grain size of the metal crystal grains is smaller than an average crystal grain size of the crystal grains in the first underlayer.

5 5. A medium according to claim 3, wherein a height of the third underlayer is 0.1 to 1 nm (inclusive).

 6. A medium according to claim 1, further comprising a nonmagnetic interlayer formed between the
10 multilayered underlayer and the perpendicular magnetic recording layer, made of at least one of ruthenium and titanium, and containing crystal grains with a hexagonal close-packed structure substantially aligned in the (0001) plane.

15 7. A medium according to claim 1, further comprising a seed layer formed between the multilayered underlayer and the soft magnetic layer, and containing at least one material selected from the group consisting of platinum, palladium, nickel,
20 nickel-iron, cobalt, titanium, and titanium nitride.

 8. A medium according to claim 1, wherein the perpendicular magnetic recording layer comprises magnetic crystal grains containing at least one of Co-Cr alloy and Co-Pt alloy as a main component, and a
25 grain boundary region containing at least one of an oxide, a nitride, and a carbide as a main component.

 9. A magnetic recording/reproducing apparatus

comprising:

- a magnetic recording medium comprising
- a substrate,
- a soft magnetic layer formed on the substrate,
- 5 a multilayered underlayer comprising a first underlayer formed on the soft magnetic layer, containing copper as a main component, and containing crystal grains with a face-centered cubic lattice structure substantially aligned in a (111) plane, and
- 10 a second underlayer formed on the first underlayer and containing copper and nitrogen as main components, and
- a perpendicular magnetic recording layer formed on the multilayered underlayer, containing cobalt as a main component, and containing crystal grains with a
- 15 hexagonal close-packed structure substantially aligned in a (0001) plane; and
- a recording/reproducing head.